

SBL1630PT - SBL1660PT

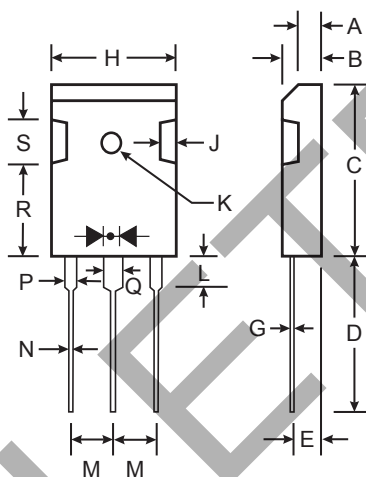
16A SCHOTTKY BARRIER RECTIFIER

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- **Lead Free Finish, RoHS Compliant (Note 3)**

Mechanical Data

- Case: TO-3P
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Bright Tin. Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Ordering Information: See Last Page
- Marking: Type Number
- Weight: 5.6 grams (approximate)



TO-3P		
Dim	Min	Max
A	1.88	2.08
B	4.68	5.36
C	20.63	22.38
D	18.5	21.5
E	2.1	2.4
G	0.51	0.76
H	15.38	16.25
J	1.90	2.70
K	2.9 \varnothing	3.65 \varnothing
L	3.78	4.50
M	5.2	5.7
N	0.89	1.53
P	1.82	2.46
Q	2.92	3.23
R	11.70	12.84
S	—	6.10
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	SBL 1630PT	SBL 1635PT	SBL 1640PT	SBL 1645PT	SBL 1650PT	SBL 1660PT	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	30	35	40	45	50	60	V
Working Peak Reverse Voltage	V _{RWM}							
DC Blocking Voltage	V _R							
RMS Reverse Voltage	V _{R(RMS)}	21	24.5	28	31.5	35	42	V
Average Rectified Output Current (Note 1)	I _o	16						A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	250						A
Forward Voltage Drop @ I _F = 8.0A, T _C = 25°C	V _{FM}	0.55				0.70		V
Peak Reverse Current @ T _C = 25°C at Rated DC Blocking Voltage @ T _C = 100°C	I _{RM}	0.5				50		mA
Typical Total Capacitance (Note 2)	C _T	700						pF
Typical Thermal Resistance Junction to Case (Note 1)	R _{θJC}	3.5						°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150						°C

- Notes:
1. Thermal resistance junction to case mounted on heatsink.
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
 3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.

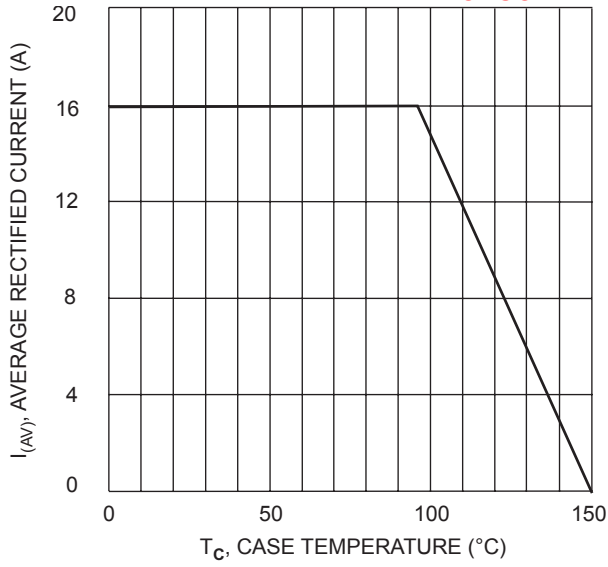


Fig. 1 Forward Current Derating Curve

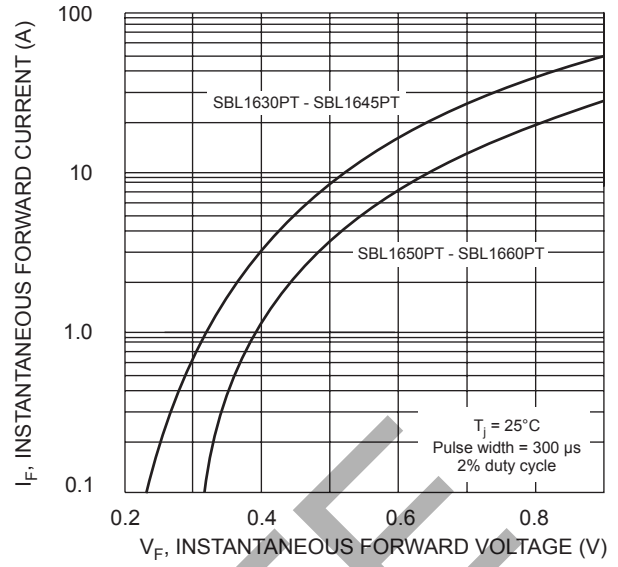


Fig. 1 Typical Forward Characteristics

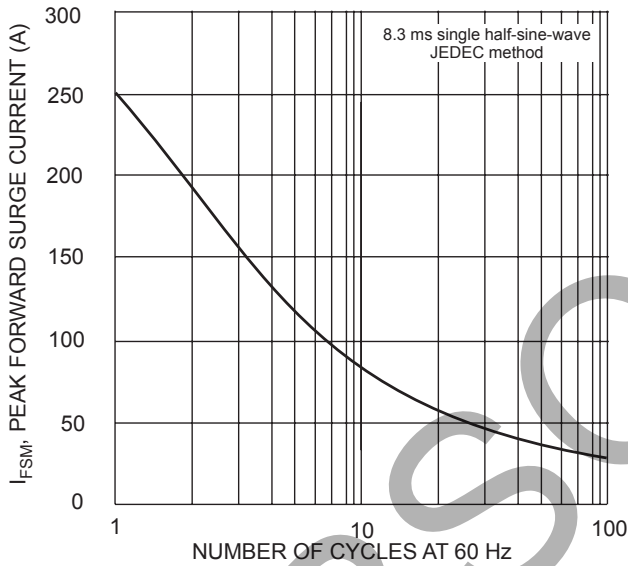


Fig. 3 Max Non-Repetitive Forward Surge Current

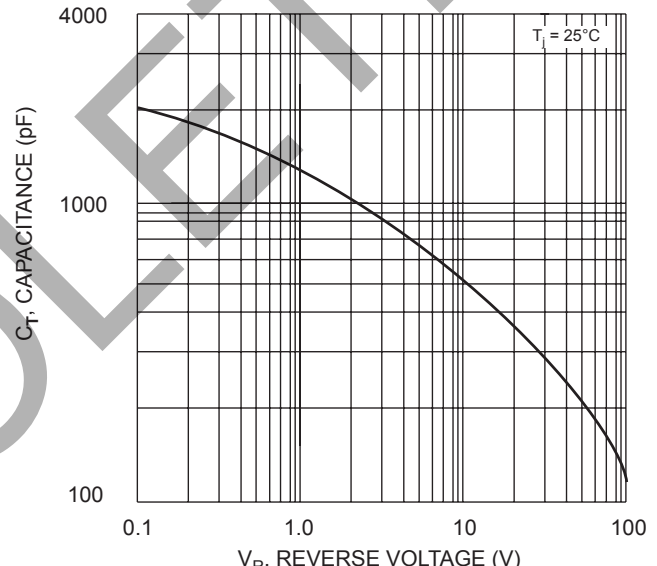


Fig. 4 Typical Total Capacitance per Element

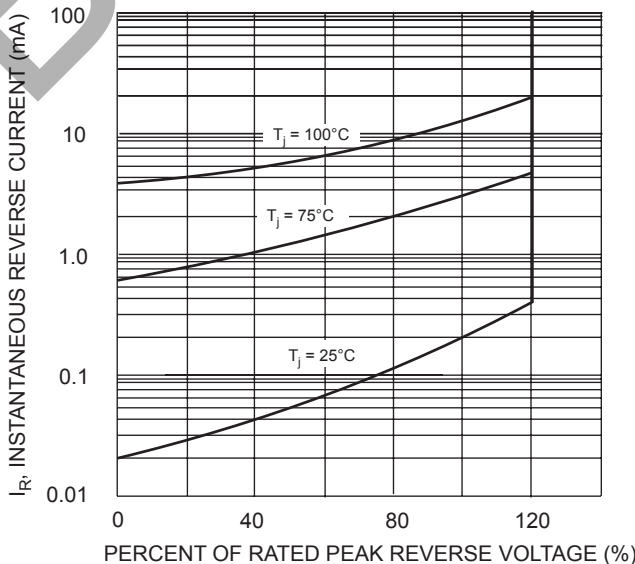


Fig. 5 Typical Reverse Characteristics per Element

Ordering Information (Note 4)

Device	Packaging	Shipping
SBL1630PT	TO-3P	30/Tube
SBL1635PT	TO-3P	30/Tube
SBL1640PT	TO-3P	30/Tube
SBL1645PT	TO-3P	30/Tube
SBL1650PT	TO-3P	30/Tube

Notes: 4. For packaging details, visit our website at <http://www.diodes.com/datasheets/ap02008.pdf>.

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